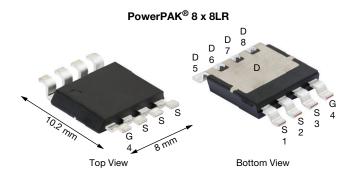


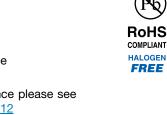
Automotive N-Channel 40 V (D-S) 175 °C MOSFET

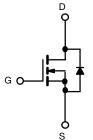


PRODUCT SUMMARY					
V _{DS} (V)	40				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.0009				
I _D (A)	575				
Configuration	Single				

FEATURES

- TrenchFET® Gen IV power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Thin 1.6 mm package
- · Very low thermal resistance
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





N-Channel MOSFET

ORDERING INFORMATION	
Package	PowerPAK 8 x 8LR
Lead (Pb)-free and halogen-free	SQJQ144AER (for detailed order number please see www.vishay.com/doc?79776)

ABSOLUTE MAXIMUM RATING	15 (10 = 25 °C, unless		<u> </u>		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V_{DS}	40	V	
Gate-source voltage		V_{GS}	± 20	V	
Continuous drain current	T _C = 25 °C	ı	575		
	T _C = 125 °C	I _D	330		
Continuous source current (diode conduction)		I _S	545	А	
Pulsed drain current ^a		I _{DM}	1800		
Single pulse avalanche current	l 0.1 ml l	I _{AS}	60		
Single pulse avalanche energy	L = 0.1 mH	E _{AS}	180	mJ	
Maximum power dissipation	T _C = 25 °C	D	600	10/	
	T _C = 125 °C	P_{D}	200	W	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	
Soldering recommendations (peak temperature) c		-	260		

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount b	R_{thJA}	44	°C/W	
unction-to-case (drain)		R_{thJC}	0.25	C/VV	

Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- b. When mounted on 1" square PCB (FR4 material)
- c. See solder profile (www.vishay.com/doc?73257). The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection



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Vishay Siliconix

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static								
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0$, $I_D = 250 \mu A$		40	-	-	V	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	- V _{GS} , I _D = 250 μA	2	3	3.5	V	
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, V _{GS} = ± 20 V	-	-	± 100	nA	
Zero gate voltage drain current		$V_{GS} = 0 V$	V _{DS} = 40 V	-	-	1		
	I _{DSS}	V _{GS} = 0 V	V _{DS} = 40 V, T _J = 125 °C	-	-	50	μΑ	
		V _{GS} = 0 V	V _{DS} = 40 V, T _J = 175 °C	-	-	150		
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 \text{ V}$	100	-	-	Α	
Drain-source on-state resistance ^a		V _{GS} = 10 V	I _D = 20 A	-	0.0007	0.0009	Ω	
	R _{DS(on)}	V _{GS} = 10 V	I _D = 20 A, T _J = 125 °C	-	-	0.0015		
		V _{GS} = 10 V	I _D = 20 A, T _J = 175 °C	-	-	0.0019		
Forward transconductance b	9 _{fs}	V _{DS} = 15 V, I _D = 60 A		-	160	-	S	
Dynamic ^b								
Input capacitance	C _{iss}		V _{DS} = 25 V, f = 1 MHz	-	7220	9020	pF	
Output capacitance	C _{oss}	$V_{GS} = 0 V$		-	2290	2860		
Reverse transfer capacitance	C _{rss}			-	175	220		
Total gate charge ^c	Qg			-	116	145		
Gate-source charge c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 20 \text{ V}, I_{D} = 30 \text{ A}$	-	36	-	nC	
Gate-drain charge ^c	Q _{gd}				25	-	1	
Gate resistance	R_g	f = 1 MHz		0.9	1.6	2.6	Ω	
Turn-on delay time c	t _{d(on)}			-	17	27		
Rise time ^c	t _r	V_{DD} = 20 V, R_L = 0.66 Ω I_D \cong 30 A, V_{GEN} = 10 V, R_g = 1 Ω		-	27	41	ns	
Turn-off delay time ^c	t _{d(off)}			-	41	62		
Fall time ^c	t _f			-	18	27		
Source-Drain Diode Ratings and Cha	racteristics b							
Reverse recovery time	t _{rr}	V _{DD} = 32 V, I _{FM} = 15 A, di/dt = 100 A/μs		-	66	-	ns	
Reverse recovery charge	Q _{rr}			-	94	-	nC	
Reverse recovery current	I _{RM}			-	-	-3.6	Α	
Pulsed current ^a	I _{SM}			-	-	1600	Α	
		$I_F = 50 \text{ A}, V_{GS} = 0$						

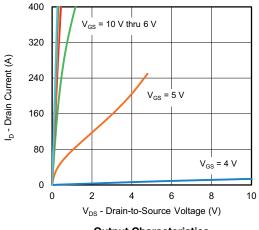
Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

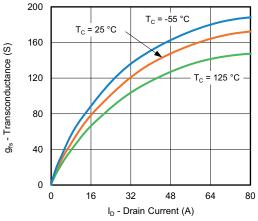
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



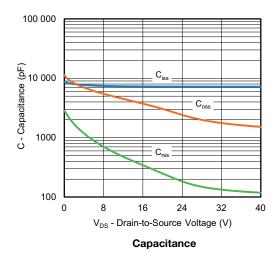
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

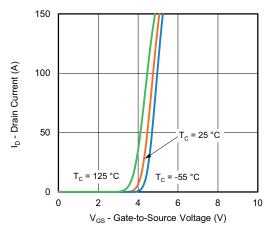


Output Characteristics

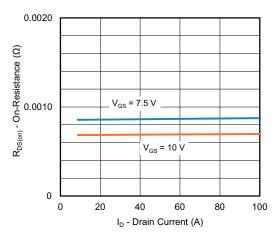


Transconductance

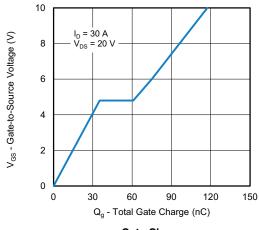




Transfer Characteristics

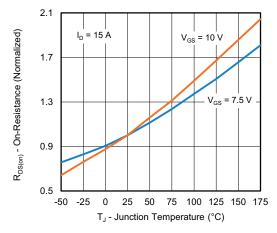


On-Resistance vs. Drain Current

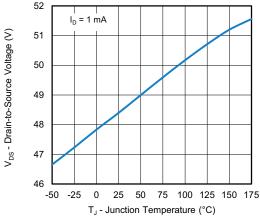




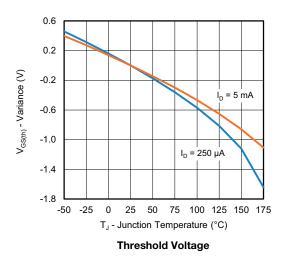
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

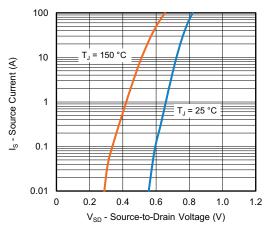


On-Resistance vs. Junction Temperature

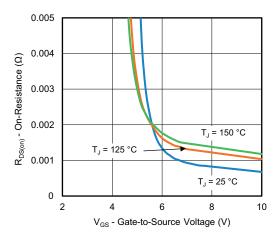


Drain Source Breakdown vs. Junction Temperature

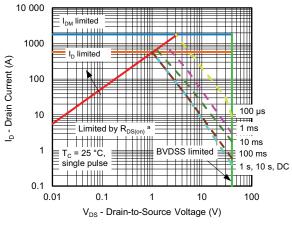




Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



Safe Operating Area

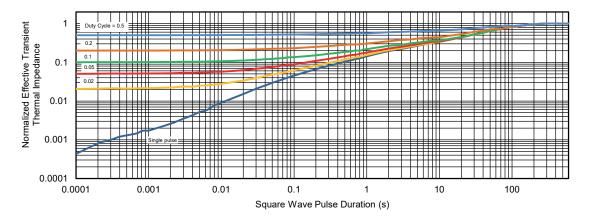
Note

a. V_{GS} > minimum V_{GS} at which R_{DS(on)} is specified

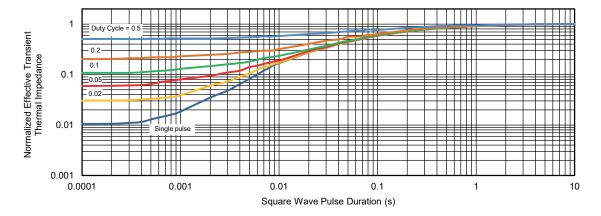
For technical questions, contact: automostech



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient

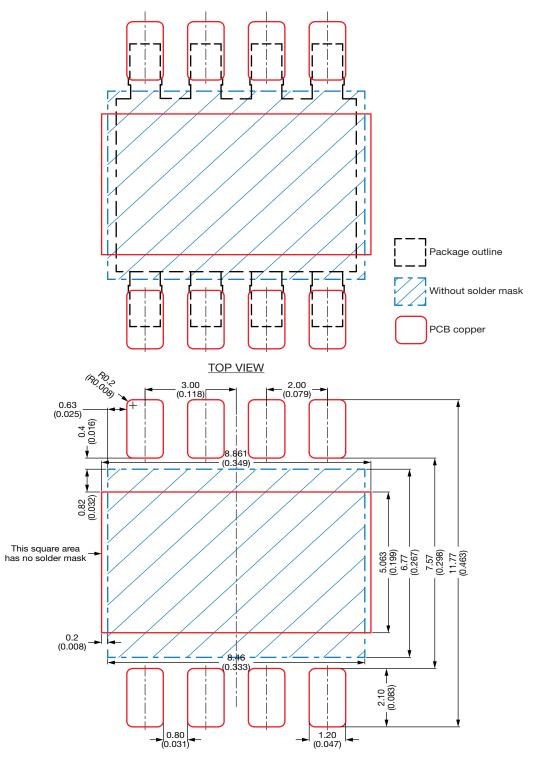


Normalized Thermal Transient Impedance, Junction-to-Case

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Recommended Land Pattern PowerPAK® 8 x 8LR



Notes

- This land pattern is for reference
- Proposed stencil thickness 200 µm All dimensions are in millimeter (inches)

ECN: C23-0461-Rev. B, 17-Apr-2023

DWG: 3002

Revision: 17-Apr-2023

Document Number: 63166



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